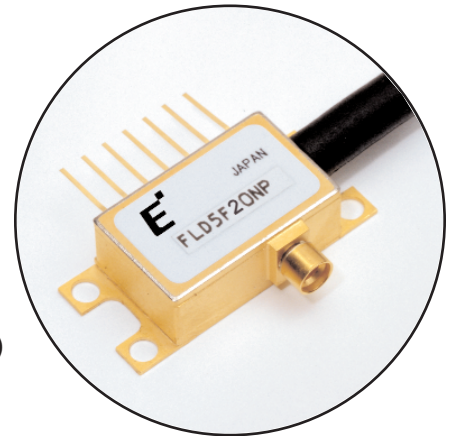


1,550nm Modulator Integrated DFB Laser

FLD5F20NP

FEATURES

- Modulator Integrated DFB Laser Diode Module
- CW operation of DFB laser section
- Modulation voltage applied only to modulator section
- High speed butterfly package with GPO connection
- Built-in optical isolator, monitor photodiode, thermistor, and thermo-electric cooler



APPLICATION

This MI laser is intended for intermediate reach applications ($\leq 40\text{km}$) at 10Gb/s.

DESCRIPTION

The Modulator Integrated DFB Laser (MI DFB Laser) has an electro-absorption modulator monolithically integrated with a conventional Distributed Feed-Back (DFB) laser. The modulation voltage is applied to the modulator section while the laser section operates CW allowing extremely low wavelength chirping. Extinction ratios of more than 10 dB can be achieved with 2.6 Vp-p modulation. The MI laser is installed in a butterfly type package. The module incorporates a highly stable optical coupling system. The module includes an optical isolator, monitor photodiode, thermistor and a thermo-electric cooler.

ABSOLUTE MAXIMUM RATINGS ($T_{\text{op}}=25^{\circ}\text{C}$, unless otherwise specified)

Parameter	Symbol	Condition	Rating		Unit
			Min.	Max.	
Operating Case Temperature	T_{op}	-	-20	+70	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-	-40	+85	$^{\circ}\text{C}$
Optical Output Power	P_{f}	CW	-	5	mW
Laser Forward Current	I_{F}	CW	-	150	mA
Laser Reverse Voltage	V_{R}	CW	-	2	V
Modulator Forward Voltage	V_{m}	CW	-5	+1	V
Photodiode Forward Current	-	-	-	1	mA
Photodiode Reverse Voltage	V_{DR}	-	-	10	V
TEC Voltage	V_{c}	Cooling	-	+2.5	V
		Heating	-2.5	-	
TEC Current	I_{c}	Cooling	-	+1.4	A
		Heating	-0.9	-	
Thermistor Temperature	T_{th}	ATC Operation	-20	+70	$^{\circ}\text{C}$
Lead Soldering Time	-	260 $^{\circ}\text{C}$	-	10	sec

OPTICAL & ELECTRICAL CHARACTERISTICS (T_L = T_{set}, T_c = 25°C, BOL, unless otherwise specified)

Parameter	Symbol	Test Condition	Limits			Unit
			Min.	Type	Max.	
Peak Wavelength	λ_p	Note (2)	1530	-	1565	nm
Threshold Current	I _{th}	CW, V _m =V _o	-	-	30	mA
Operating Current	I _{op}	-	40	-	100	mA
Forward Voltage	V _F	CW, I _F =I _{op}	-	1.4	2.0	V
Optical Output Power (Avg. Power)	P _f	Note (2)	0	-	-	dBm
Dispersion Penalty	dP	Note (1)	-	-	2.0	dB
Sidemode Suppression Ratio	SSR	Note (2)	35	-	-	dB
Optical Isolation	I _s	T _c =-20 to +70°C	25	35	-	dB
On Level Modulation	V _o	-	-0.7	-	0	V
Modulator Drive Voltage	V _{mod}	(V _o -V _{mod})≥-3.3V, R _{ext} =10dB	-	-	2.6	V
Extinction Ratio	R _{ext}	f=10Gb/s, I _F =I _{op} , V _m =V _o /(V _o -V _{mod})	10	-	-	dB
Rise Time	T _r	I _F =I _{op} , V _m =V _o , 20 to 80%	-	20	25	ps
Fall Time	T _f		-	20	25	ps
In-Band Ripple	ΔG	I _F =I _{op} , f=0.1-10GHz, V _m =V _o -0.5(V _{mod})	-	-	±1.0	dB
RF Return Loss	S ₁₁	f=DC-5GHz, 50Ω Test Set, V _m =V _o , I _F =I _{op}	8	-	-	dB
RF Return Loss	S ₁₁	f=5-10GHz, 50Ω Test Set, V _m =V _o , I _F =I _{op}	5	-	-	dB
Monitor Current	I _m	CW, I _F =I _{op} , V _m =V _o , V _D R=5V	0.04	-	1.5	mA
Cut-off Frequency	S ₂₁	-3dB bandwidth, V _m =V _o -0.5(V _{mod}), I _F =I _{op}	10	-	-	GHz
Relative Intensity Noise	RIN	f=10 MHz to 8.5 GHz, V _m =V _o , I _F =I _{op} , 8% Reflection	-	-	-120	dB/Hz
TEC Capacity	ΔT	P _{TEC} =2.4W, I _F =I _{op}	45	-	-	°C
TEC Current	I _c	I _F =I _{op} , T=45°C	-	-	1.0	A
TEC Voltage	V _c	I _F =I _{op} , ΔT=45°C	-	-	2.4	V
TEC Power Dissipation	P _c	I _F =I _{op}	-	-	2.4	W
Thermal Resistance	R _{th}	T _L =25°C, T _c =+25°C	9.5	10.0	10.5	kΩ
Thermistor B Constant (Note 3)	B		3,270	3,450	3,630	K

Note (1) Eudyna Test System
9.95328Gb/s, PRBS=2²³-1, I_F=I_{op}, V_m=V_o and (V_o-V_{mod})
Dispersion=800ps/nm, Dispersion penalty at
Bit Error Rate=1.0E-10

Note (2) Eudyna Test System
9.95328Gb/s, PRBS=2²³-1, I_F=I_{op}, V_m=V_o and (V_o-V_{mod})

Note (3) Relation between resistance and temperature (°K) is: R_{th}(T)=R_{th}(25°C)*exp[B(1/T-1/298)]

Fig. 1 Lasing Spectrum

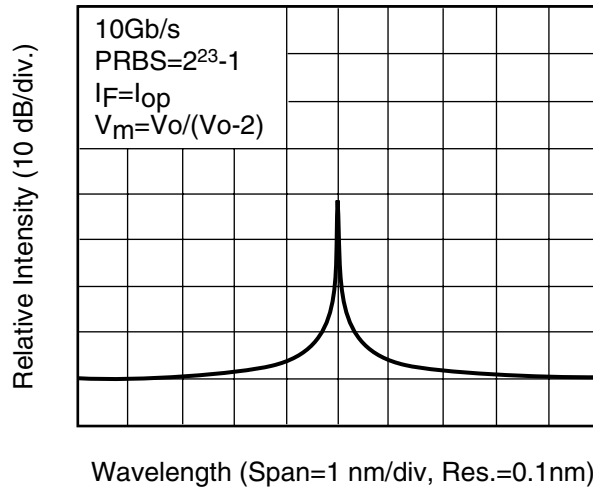


Fig. 2 Output Power & Monitor Current vs. Forward Current

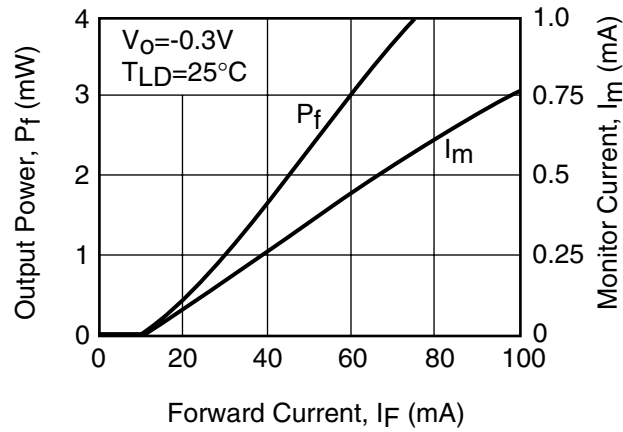


Fig. 3 Extinction Ratio vs. Modulation Applied Voltage

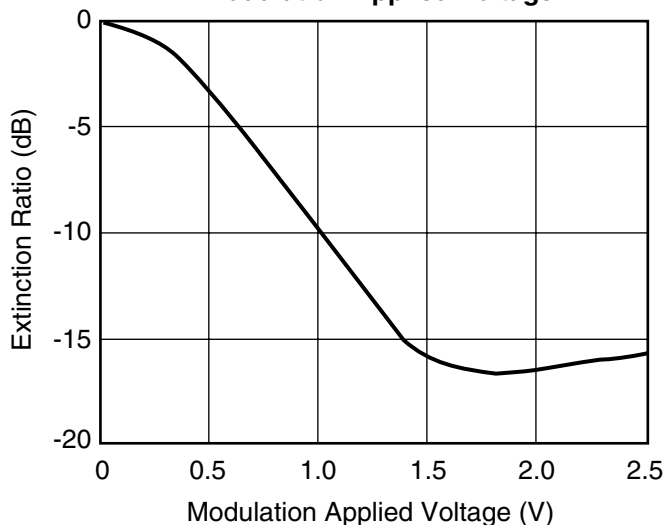


Fig. 4 Cut-off Frequency (S21)

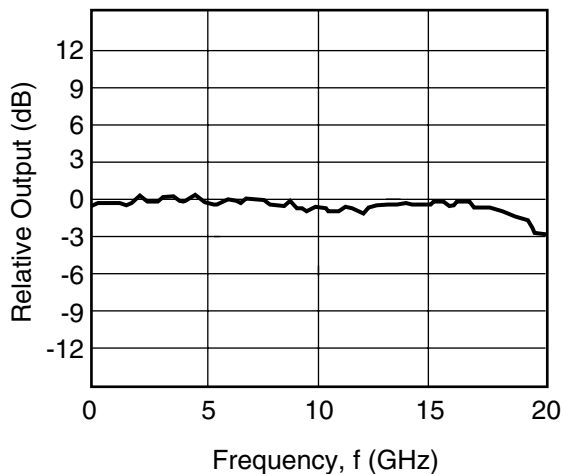


Fig. 5 RF Return Loss (S11)

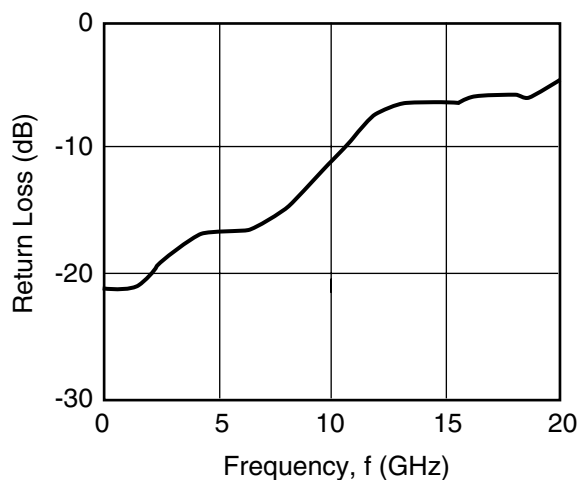


Fig. 6 Transmission Characteristics

